

# STPS3045C-Y

# Automotive power Schottky rectifier

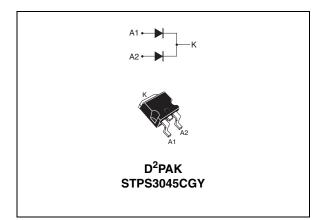
## Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- Avalanche rated
- AEC-Q101 qualified

## Description

This device is a dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in D<sup>2</sup>PAK, this device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



### Table 1. Device summary

	-
I <sub>F(AV)</sub>	2 x 15 A
V <sub>RRM</sub>	45 V
T <sub>j (max)</sub>	175 °C
V <sub>F (max)</sub>	0.57 V

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# 1 Characteristics

Symbol	Paramete	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage			45	V
I <sub>F(RMS)</sub>	Forward rms voltage			30	А
I <sub>F(AV)</sub>	Average forward current $\delta = 0.5$	$T_{C} = 155 \ ^{\circ}C \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$		10 30	А
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms s	inusoidal	220	А
P <sub>ARM</sub>	Repetitive peak avalanche power	epetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25 \ ^{\circ}C$			W
T <sub>stg</sub>	Storage temperature range			-65 to +175	°C
Тj	Maximum operating junction temperature <sup>(1)</sup>			-40 to +175	°C
dV/dt	Critical rate of rise reverse voltage			10000	V/µs
dDtot	4				

### Table 2.Absolute ratings (limiting values, per diode)

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

## Table 3. Thermal resistance parameters

Symbol	Parameter		Value	Unit
R <sub>th (j-c)</sub>	Junction to case	Per diode Total	1.60 0.85	° C/W
R <sub>th (c)</sub>	Coupling		0.10	° C/W

When the diodes 1 and 2 are used simultaneously :

 $\Delta T_{j}(\text{diode 1}) = P(\text{diode1}) \times R_{\text{th}(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{\text{th}(c)}$ 

## Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	$\mathcal{M} = \mathcal{M}$	-	-	200	μA	
	neverse leakage current	T <sub>j</sub> = 125 °C	$V_{R} = V_{RRM}$	-	11	40	mA
		T <sub>j</sub> = 125 °C	l <sub>F</sub> = 15 A	-	0.5	0.57	
V <sub>F</sub> <sup>(1)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	1 20 4	-	-	0.84	V	
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 30 A	-	0.65	0.72	

1. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

 $P = 0.42 \text{ x } I_{F(AV)} + 0.01 I_{F}^{2}(RMS)$ 



Average forward current versus

ambient temperature

°C/V

Tamb(°C)

100

125

150

175

150

( $\delta$  = 0.5, per diode)

IF(AV)(A)

18

8

6

4

2

0

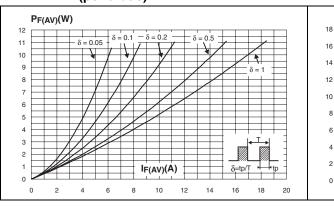
0

δ=tp/T

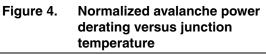
25

50

#### Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)



#### Normalized avalanche power Figure 3. derating versus pulse duration



75

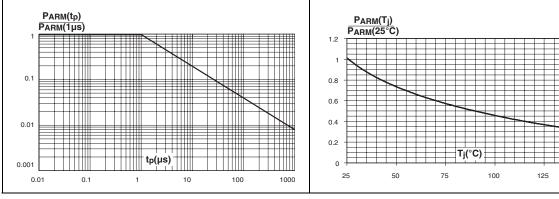


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

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**Relative variation of thermal** impedance junction to ambient versus pulse duration

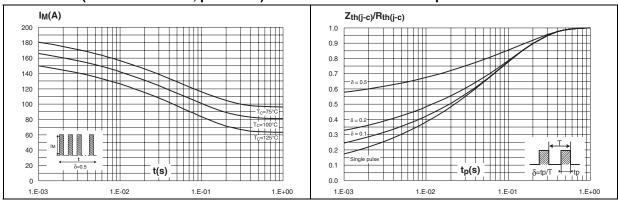
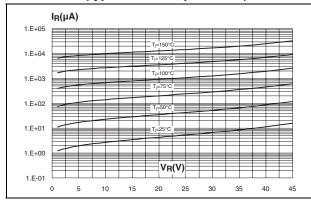


Figure 6.

# Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)



## Figure 9. Forward voltage drop versus forward current (maximum values, per diode)

# Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)

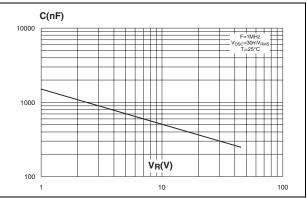
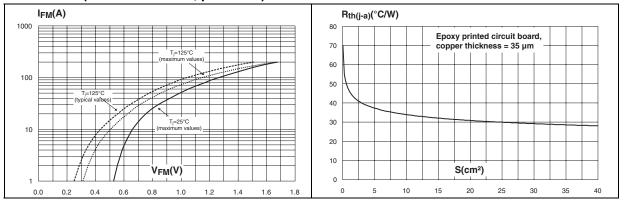


Figure 10. Thermal resistance junction to ambient versus copper surface under tab





# 2 Package information

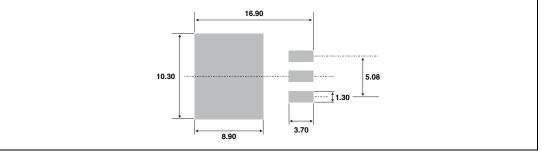
- Epoxy meets UL94,V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

Table 5.Package dimensions D2PAK

			Dimensions				
		Ref.	Millin	Millimeters		Inches	
i			Min.	Max.	Min.	Max.	
	L <b>A</b> J	Α	4.40	4.60	0.173	0.181	
E  ▲ →		A1	2.49	2.69	0.098	0.106	
		A2	0.03	0.23	0.001	0.009	
	D	В	0.70	0.93	0.027	0.037	
L		B2	1.14	1.70	0.045	0.067	
	A1.	С	0.45	0.60	0.017	0.024	
		C2	1.23	1.36	0.048	0.054	
		D	8.95	9.35	0.352	0.368	
G →!		E	10.00	10.40	0.393	0.409	
		G	4.88	5.28	0.192	0.208	
	1.	L	15.00	15.85	0.590	0.624	
	M + V2	L2	1.27	1.40	0.050	0.055	
	* FLAT ZONE NO LESS THAN 2mm	L3	1.40	1.75	0.055	0.069	
		М	2.40	3.20	0.094	0.126	
		R	0.40	) typ.	0.016	6 typ.	
		V2	0°	8°	0°	8°	







# **3** Ordering information

## Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3045CGY-TR	STPS3045CGY	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel

# 4 Revision history

## Table 7.Document revision history

Date	Revision	Changes
24-May-2011	1	Initial release.



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